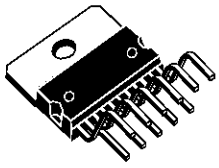
SGS-THOMSON MICROELECTRONICS

TDA7263M

12 +12W STEREO AMPLIFIER WITH MUTING

- WIDE SUPPLY VOLTAGE RANGE
- HIGH OUTPUT POWER
  12+12W @ V_S=28V, R_L = 8Ω, THD=10%
- MUTE FACILITY (POP FREE) WITH LOW CONSUMPTION
- AC SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION



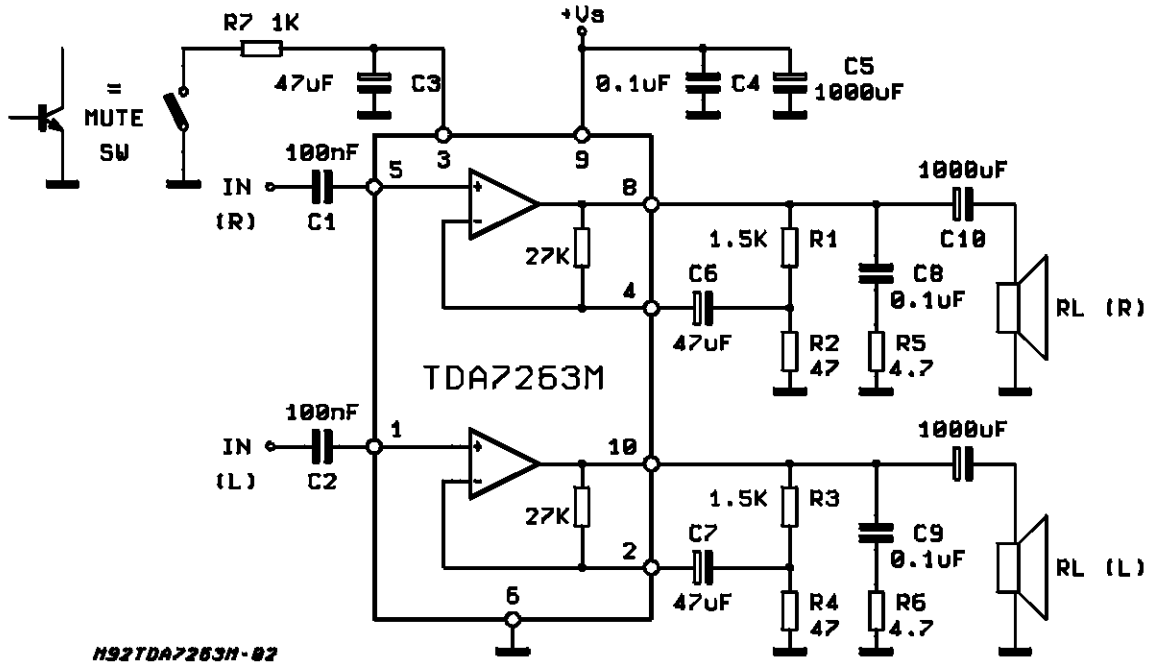
Multiwatt11

ORDERING NUMBER:TDA7263M

DESCRIPTION

The TDA7263M is class AB dual audio power amplifier assembled in the Multiwatt package, specially designed for high quality sound application as HI-FI music centers and stereo TV sets.

APPLICATION CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage	35	V
I_O	Output Peak Current (repetitive f >20Hz)	2.5	A
I_O	Output Peak Current (non repetitive, t = 100µs)	3.5	A
P_{tot}	Total Power Dissipation (T_{case} = 70°C)	30	W
T_{op}	Operating Temperature Range	0 to 70	°C
$T_{stg,Tj}$	Storage & Junction Temperature	-40 to 150	°C

PIN CONNECTION (Top view)

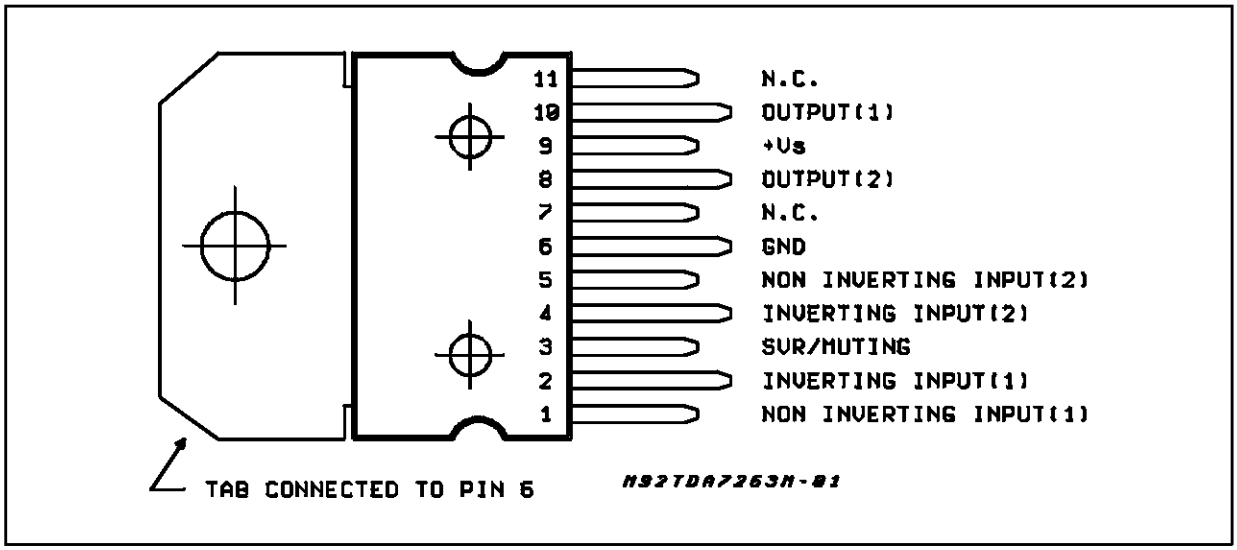
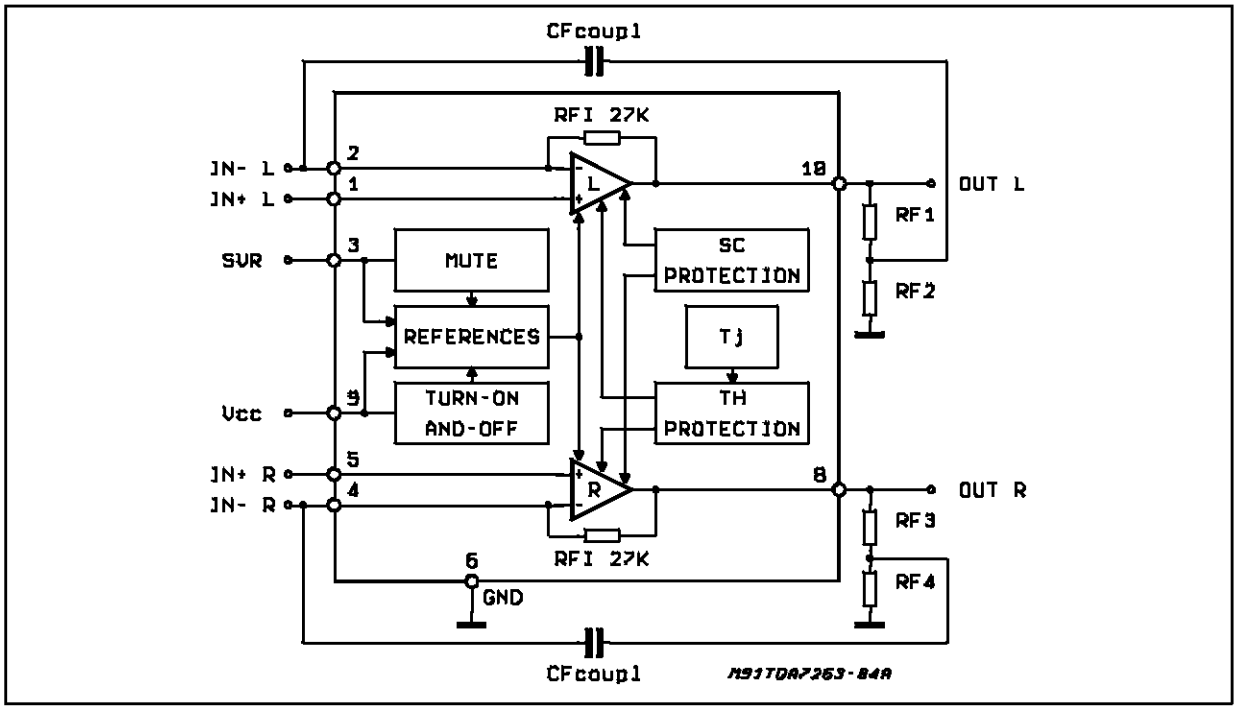


Figure 1: Block Diagram



THERMAL DATA

Symbol	Parameter		Value	Unit
$R_{th\ j\text{-}case}$	Thermal resistance junction to case	Max	2.5	°C/W

ELECTRICAL CHARACTERISTICS (Refer to the stereo test and application circuit, V_S = 28V; R_L = 8Ω; G_v = 30dB; f = 1KHz; T_{amb} = 25°C unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_S	Supply Voltage		10		32	V
V_O	Quiescent Output Voltage			13.5		V
I_q	Total Quiescent Current			70	95	mA
P_O	Output Power (RMS)	d = 10% Tamb = 85°C d = 1%	10	12 9.5		W W
d	Total Harmonic Distortion	P_O = 1W, f = 1kHz f = 100Hz to 10KHz; P_O = 0.1 to 8W		0.02	0.2 0.5	% %
CT	Cross Talk	R_S = 10KΩ; f = 1KHz		70		dB
		R_S = 10KΩ; f = 10KHz		60		dB
R_I	Input Resistance		100	200		KΩ
f_L	Low Frequency Roll-off (-3dB)			40		Hz
f_H	High Frequency Roll-off (-3dB)			80		KHz
e_N	Total Input Noise Voltage	A Curve; R_S = 10KΩ		1.5		mV
		f = 22Hz to 22KHz; R_S = 10KΩ		3	10	μV
SVR	Supply Voltage Rejection (each channel)	R_S = 10KΩ; f = 100Hz; Vr = 0.5V	45	60		dB
T_j	Thermal Shutdown Junction Temperature			145		°C
MUTE FUNCTION						
VT_{MUTE}	Mute Threshold		1	1.6		V
VT_{PLAY}	Play Threshold			4.5		V
ATT_{AM}	Mute Attenuation		70	100		dB
I_{qMUTE}	Quiescent Current @ Mute			7	10	mA

TYPICAL CHARACTERISTICS (referred to the typical Application Circuit, V_S = 28V, R_L = 8Ω, unless otherwise specified)

Figure 1: Output Power vs. Supply Voltage

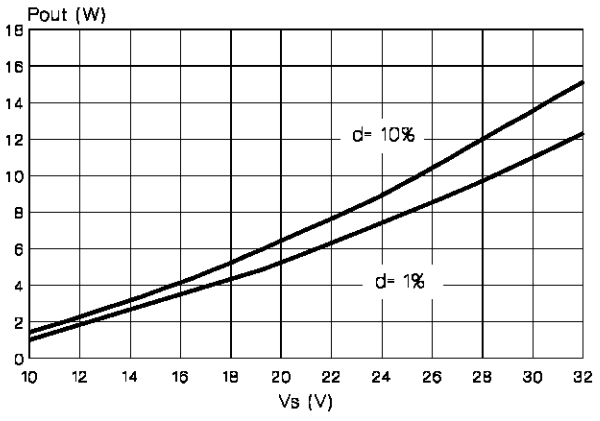


Figure 2: Distortion vs. Output Power

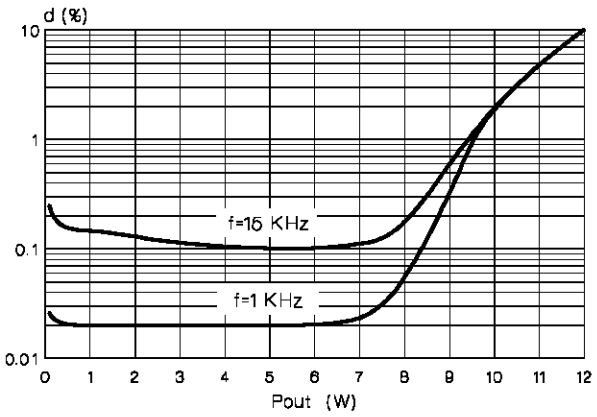


Figure 3: Quiescent Current vs. Supply Voltage

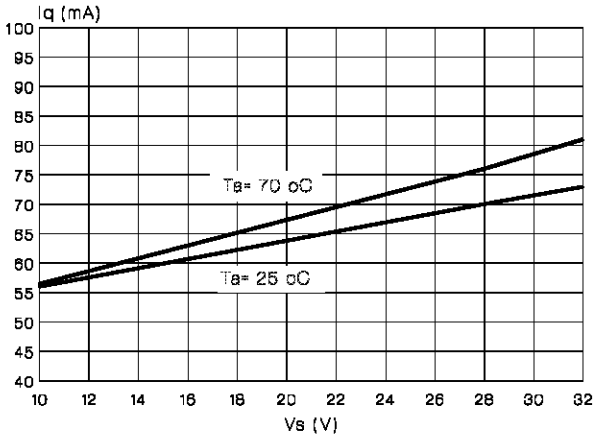


Figure 4: Supply Voltage Rejection vs. Frequency

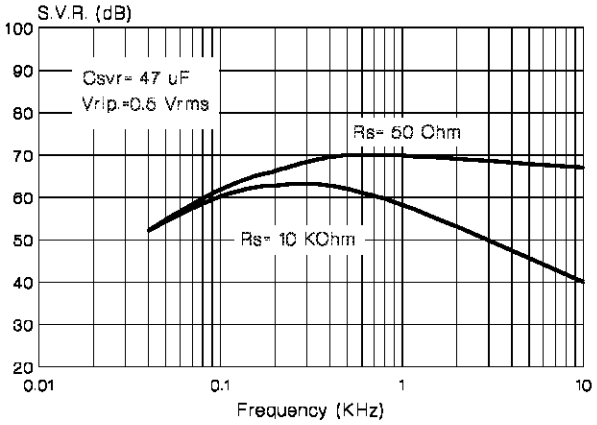


Figure 5: Crosstalk vs. Frequency

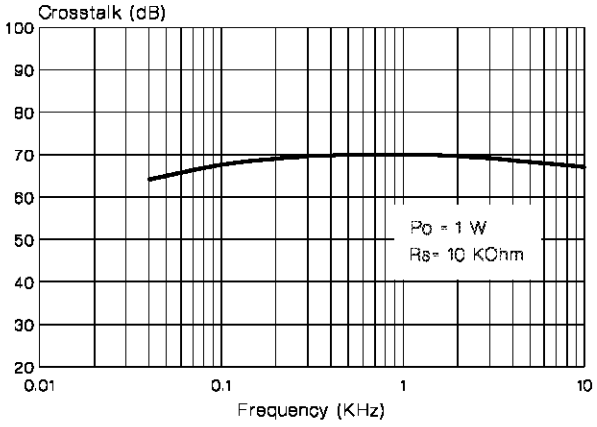


Figure 6: Output Attenuation & Quiescent Current vs. V_{pin3}

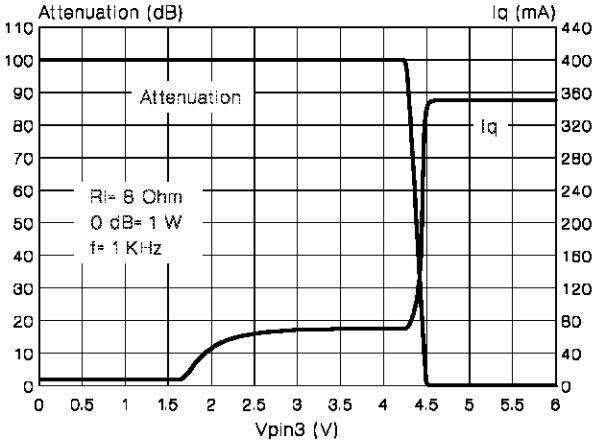
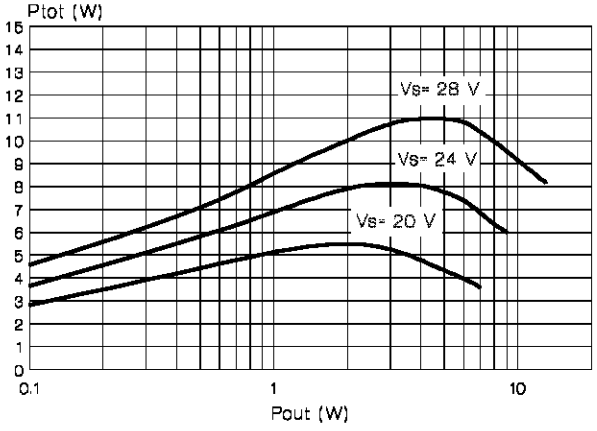


Figure 7: Total Power Dissipation vs. Output Power



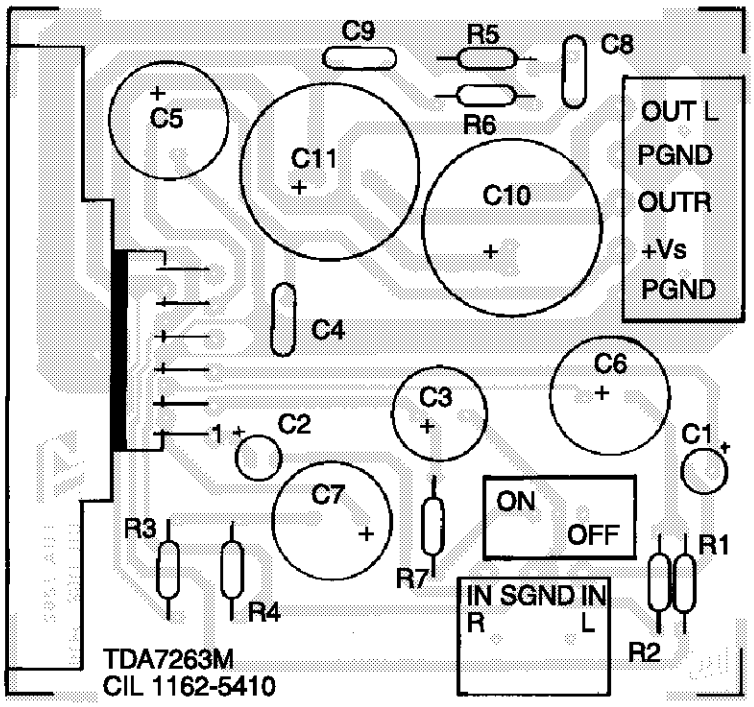
APPLICATION SUGGESTION

The recommended values of the components are those shown on application circuit of figure 1. Different values can be used; the following table can help the designer.

Component	Recomm. Value	Purpose	Larger Than	Smaller Than
R1 and R3	1.5KΩ	Close loop gain setting (*)	Increase of gain	Decrease of gain
R2 and R4	47Ω	Close loop gain setting (*)	Decrease of gain	Increase of gain
R5 and R6	4.7Ω	Frequency stability	Danger of oscillations	
C1 and C2	100nF	Input DC decoupling	Higher SVR	Higher low frequency cutoff
C3	47µF	- Ripple Rejection - Mute time constant	Increase of the Switch-on time	- Degradation of SVR - Worse turn-off pop by muting
C4	100nF	Supply Voltage Bypass		Danger of oscillations
C5	1000µF	Supply Voltage Bypass		
C6 and C7	47µF	Feedback input DC decoupling	Increase of the Switch-on time	Decrease of the Switch-on time
C8 and C9	0.1µF	Frequency stability		Danger of oscillations
C10 and C11	1000µF	Output DC decoupling		Higher low-frequency cut-off

(*) Closed loop gain must be higher than 26dB

Figure 8: P. C. Board and Component Layout of the Application Circuit (1:1 scale).



BUILT-IN PROTECTION SYSTEMS

THERMAL SHUT-DOWN

The presence of a thermal limiting circuit offers the following advantages:

1-an overload on the output (even if it is permanent), or an excessive ambient temperature can be easily withstood.

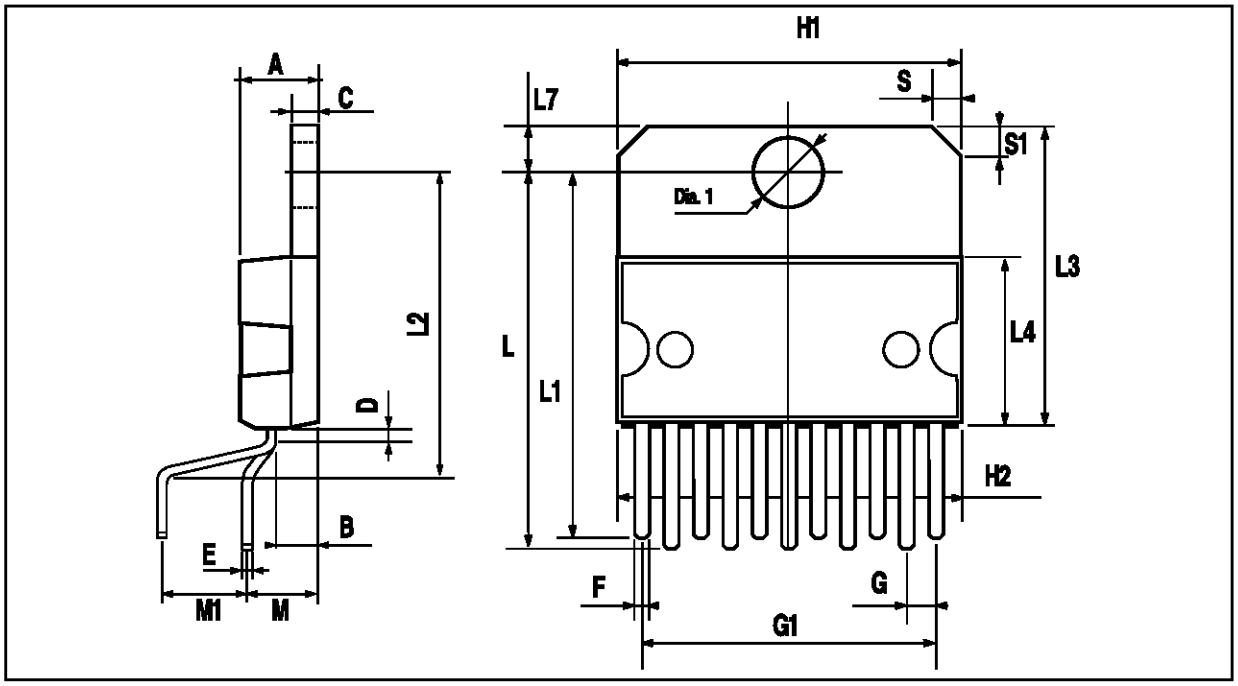
2-the heatsink can have a smaller factor of safety compared with that of a conventional circuit. There is no device damage in the case of excessive junction temperature; all that happens is that P_O (and therefore P_{tot}) and I_O are reduced.

SHORT CIRCUIT (AC CONDITIONS)

The TDA7263M can withstand accidental short circuits across the speaker made by a wrong connection during normal play operation.

MULTIWATT11 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.88		0.95	0.035		0.037
G	1.57	1.7	1.83	0.062	0.067	0.072
G1	16.87	17	17.13	0.664	0.669	0.674
H1	19.6			0.772		
H2			20.2			0.795
L	21.5		22.3	0.846		0.878
L1	21.4		22.2	0.843		0.874
L2	17.4		18.1	0.685		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.1	4.3	4.5	0.161	0.169	0.177
M1	4.88	5.08	5.3	0.192	0.200	0.209
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152



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